

Vishay Semiconductors

Small Signal Switching Diode, Dual



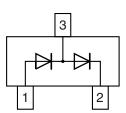
GS18/10K per 13" reel (8 mm tape), 10K/box GS08/3K per 7" reel (8 mm tape), 15K/box

MECHANICAL DATA

Weight: approx. 8.8 mg Packaging codes/options:

Case: SOT-23

MMBD7000-V



MMBD7000-V-GS18 or MMBD7000-V-GS08

FEATURES

- Silicon epitaxial planar diode
- Fast switching dual diode, especially suited for automatic insertion

Dual diodes serial

- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912





Tape and reel

 PARTS TABLE

 PART
 ORDERING CODE
 TYPE MARKING
 INTERNAL CONSTRUCTION
 REMARKS

M5C

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Reverse voltage		V _R	100	V			
Forward current (continuous)		I _F	200	mA			
Non-repetitive peak forward current	t = 1 s	I _{FSM}	500	mA			
Power dissipation on FR-5 board		P _{tot}	225	mW			
	Derate above 25 °C	P _{tot}	1.8	mW/K			
Total device dissipation on Alumina substrate		P _{tot}	300	mW			
	Derate above 25 °C	P _{tot}	2.4	mW/K			

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
Typical thermal resistance, junction to ambient air		R _{thJA} ⁽¹⁾	417	K/W				
		R _{thJA} ⁽²⁾	556	K/W				
Maximum junction temperature		Tj	150	°C				
Storage temperature range		T _{stg}	- 55 to + 150	°C				

Notes

⁽¹⁾ Device on alumina substrate

(2) On FR-5 board

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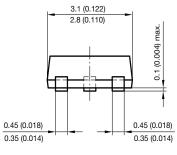
SHA

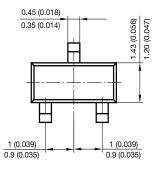
MMBD7000-V

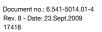
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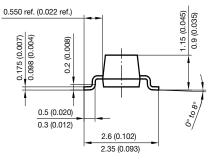
ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Reverse breakdown voltage	I _R = 100 μA	V _(BR)				V		
Leakage current	$V_R = 50 V$	I _R			1	μA		
	V _R = 100 V	I _R			3	μA		
	$V_R = 50 \text{ V}, \text{ T}_j = 125 \text{ °C}$	I _R			100	μA		
Forward voltage	$I_F = 1 \text{ mA}$	VF	0.55		0.70	V		
	l _F = 10 mA	V _F	0.67		0.82	V		
	I _F = 100 mA	V _F	0.75		1.10	V		
Diode capacitance	$V_{R} = 0, f = 1 MHz$	CD			1.5	pF		
Reverse recovery time	$I_F = 10 \text{ mA}, i_R = 1 \text{ mA}, R_L = 100 \Omega$	t _{rr}			4	ns		

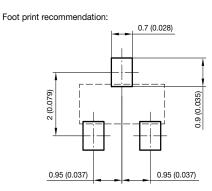
PACKAGE DIMENSIONS in millimeters (inches): SOT-23













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